

Fig. S-1

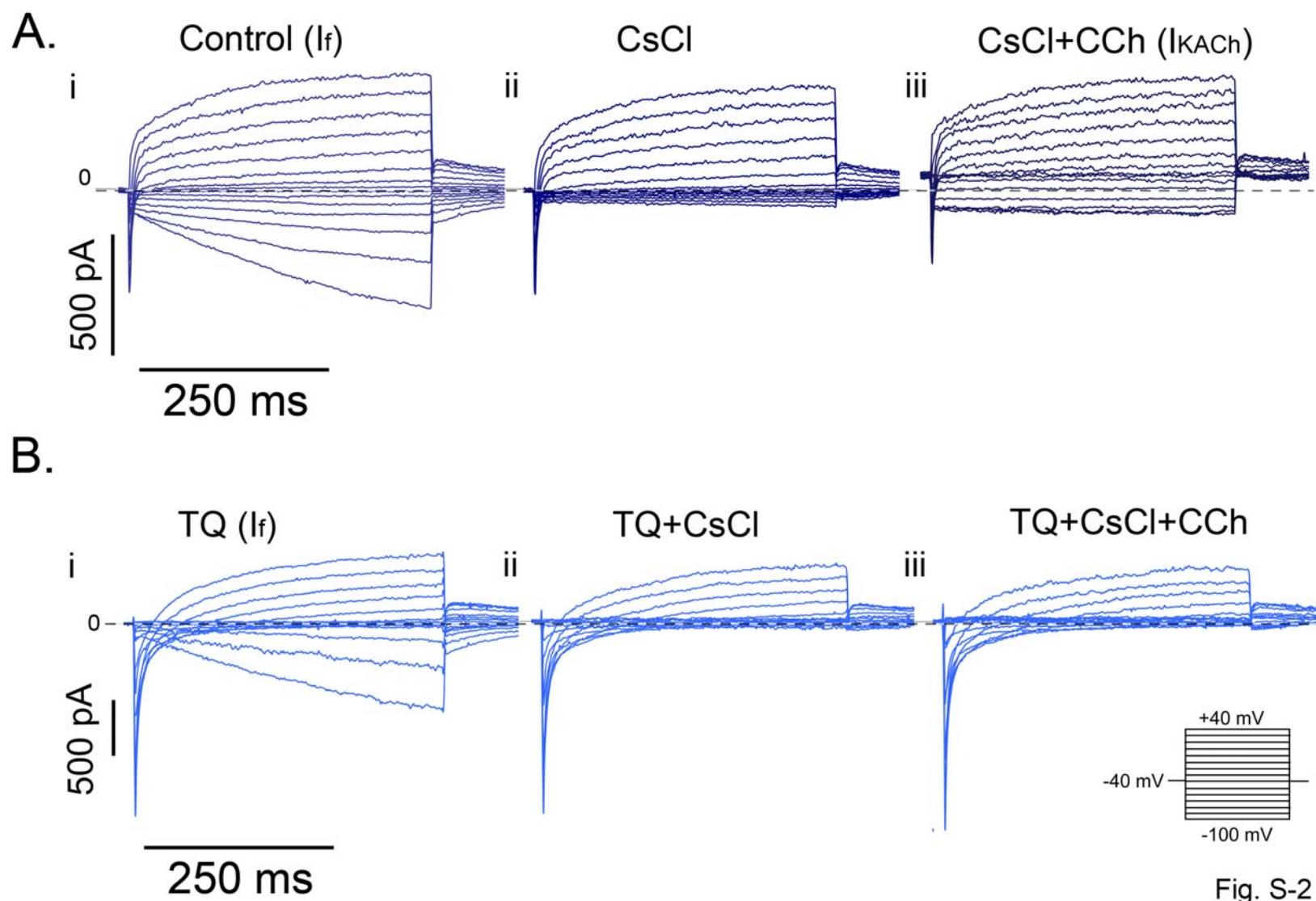


Fig. S-2

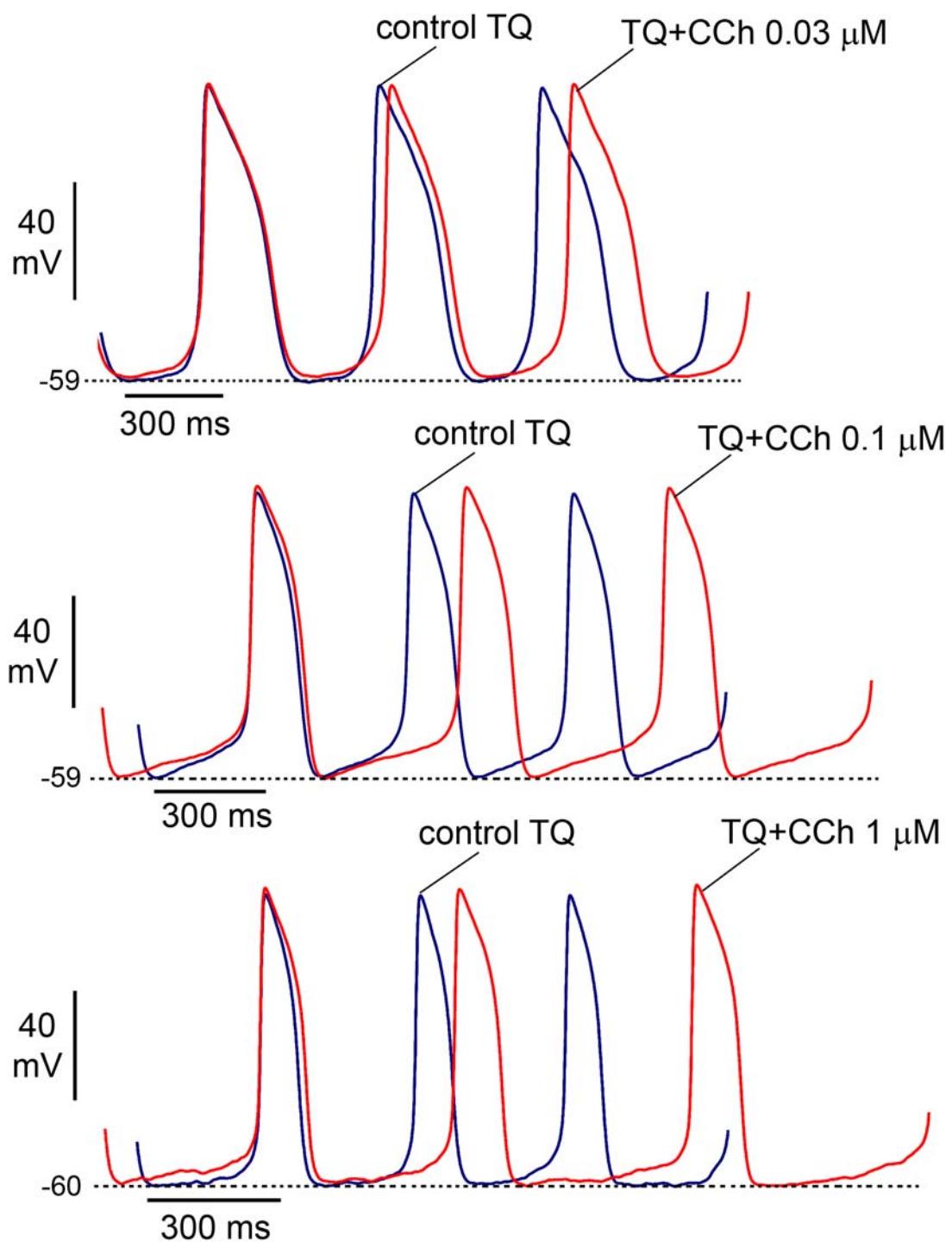


Fig. S-3

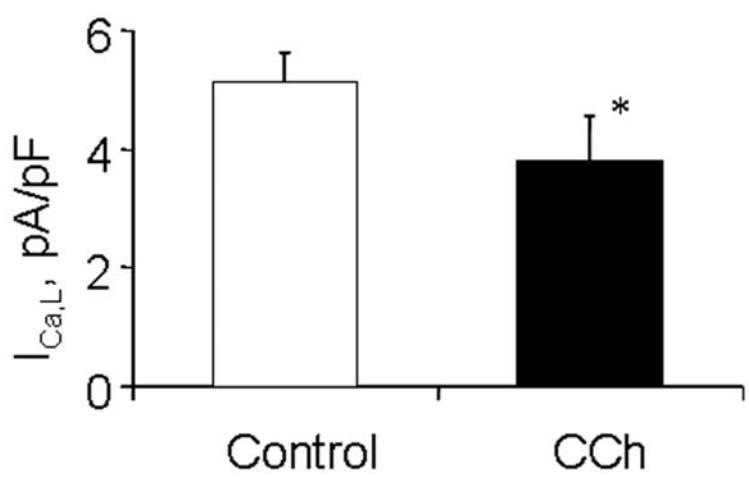
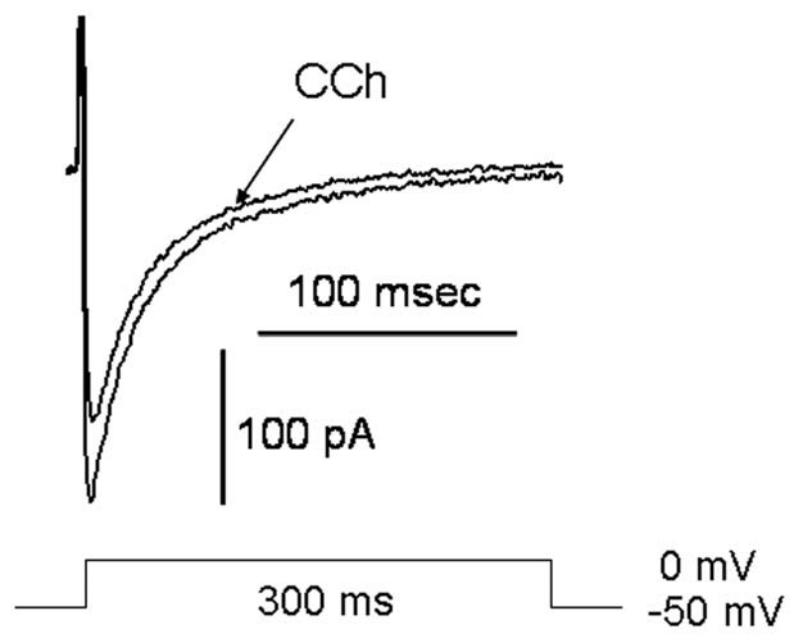


Fig. S-4

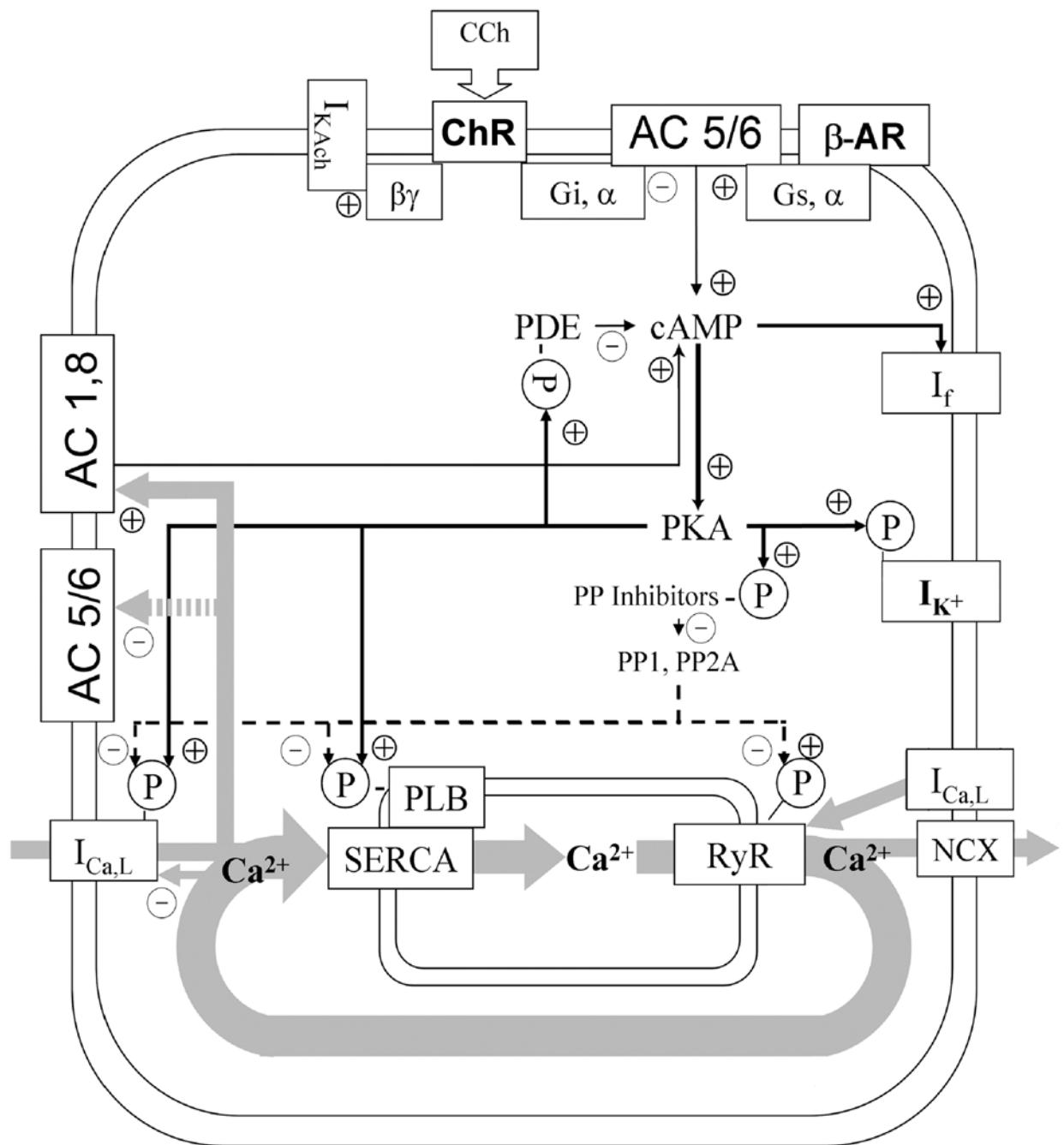


Fig. S-5

Table S-1 Effect of 100 nM CCh on AP parameters

	Control	CsCl	CCh	CsCl+CCh	TQ	TQ+CsCl	TQ+CCh	TQ+CsCl+CCh
Period, ms	313±32	333±14.0*	1130±106.0*	1017±43.0*	299±10.9	296±29.8	381±21.3*	380±50.0*
MDP, mV	-61.7±1.4	-60.7±1.4	-63.2±0.8*	-62.5±2.1*	-59.8±1.1	-60.7±0.2	-59.9±1.1	-60.2±0.2
dV/dt max, V/s	5.3±1.1	6.1±1.5	6.6±1.1	7.3±0.7	7.6±0.4	7.2±0.3	7.8±0.5	7.3±0.3